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General Purpose Transistors

NPN Silicon

Features

• These are Pb–Free Devices

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector-Base Voltage	V _{CBO}	60	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ι _C	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $@T_A = 25^{\circ}C$ Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

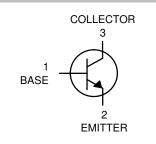
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

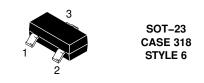
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



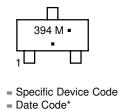
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



M = Date Code* = Pb-Free Package

394

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NSCT3904LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
NSCT3904LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

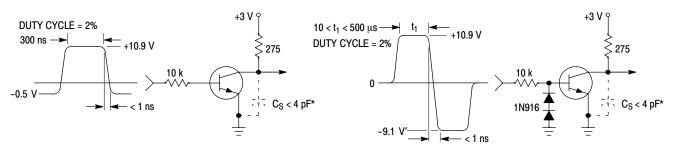
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Chara	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS		•			
Collector-Emitter Breakdown Voltage (Ic	V _{(BR)CEO}	40	-	Vdc	
Collector – Base Breakdown Voltage (I _C =	= 10 μAdc, I _E = 0)	V _{(BR)CBO}	60	-	Vdc
Emitter-Base Breakdown Voltage (I _E = ⁻	10 μAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Base Cutoff Current (V_{CE} = 30 Vdc, V_{EB}	= 3.0 Vdc)	I _{BL}	-	50	nAdc
Collector Cutoff Current (V _{CE} = 30 Vdc, V	ICEX	-	50	nAdc	
ON CHARACTERISTICS (Note 3)					
	H _{FE}	40 70 100 60 30	_ 300 _ _	_	
$\begin{array}{l} \mbox{Collector}-\mbox{Emitter Saturation Voltage} \\ (I_C = 10 \mbox{ mAdc}, I_B = 1.0 \mbox{ mAdc}) \\ (I_C = 50 \mbox{ mAdc}, I_B = 5.0 \mbox{ mAdc}) \end{array}$	V _{CE(sat)}		0.2 0.3	Vdc	
$\begin{array}{l} \text{Base-Emitter Saturation Voltage} \\ (I_{C} = 10 \text{ mAdc}, I_{B} = 1.0 \text{ mAdc}) \\ (I_{C} = 50 \text{ mAdc}, I_{B} = 5.0 \text{ mAdc}) \end{array}$	V _{BE(sat)}	0.65 _	0.85 0.95	Vdc	
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain - Bandwidth Product (I _C =	= 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)	f _T	300	-	MHz
Output Capacitance ($V_{CB} = 5.0$ Vdc, $I_E =$: 0, f = 1.0 MHz)	C _{obo}	-	4.0	pF
Input Capacitance ($V_{EB} = 0.5$ Vdc, $I_C = 0.5$), f = 1.0 MHz)	C _{ibo}	-	8.0	pF
Input Impedance (V_{CE} = 10 Vdc, I_{C} = 1.0) mAdc, f = 1.0 kHz)	h _{ie}	1.0	10	kΩ
Voltage Feedback Ratio (V _{CE} = 10 Vdc,	h _{re}	0.5	8.0	X 10 ⁻⁴	
Small-Signal Current Gain (V _{CE} = 10 Vo	dc, I _C = 1.0 mAdc, f = 1.0 kHz)	h _{fe}	100	400	-
Output Admittance ($V_{CE} = 10$ Vdc, $I_{C} = 1$	h _{oe}	1.0	40	μmhos	
Noise Figure (V _{CE} = 5.0 Vdc, I_C = 100 μ /	NF	-	5.0	dB	
SWITCHING CHARACTERISTICS		•	•	•	•
Delay Time	(V _{CC} = 3.0 Vdc, V _{BE} = -0.5 Vdc,	t _d	-	35	
Rise Time	$I_{\rm C} = 10 \text{ mAdc}, I_{\rm B1} = 1.0 \text{ mAdc})$	t _r	-	35	ns

3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

Storage Time

Fall Time



 $(V_{CC}=3.0~Vdc, \label{eq:V_CC} I_C=10~mAdc, \ I_{B1}=I_{B2}=1.0~mAdc)$

* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit Figure 2. Storage and Fall Time Equivalent Test Circuit

200

50

ns

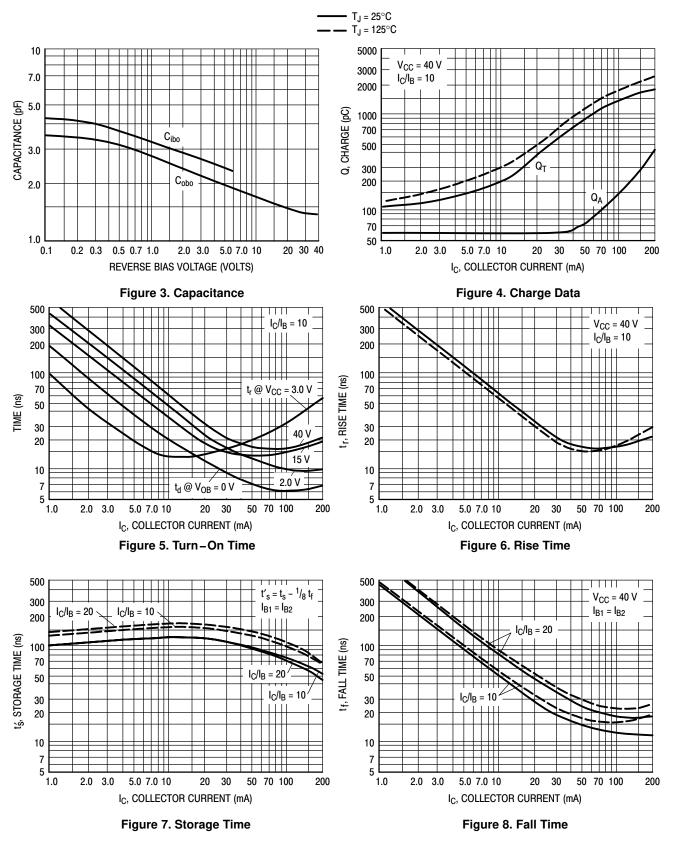
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ts

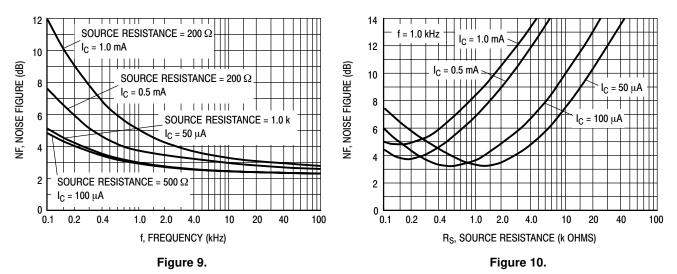
t_f

TYPICAL TRANSIENT CHARACTERISTICS



TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C, Bandwidth = 1.0 \text{ Hz})$



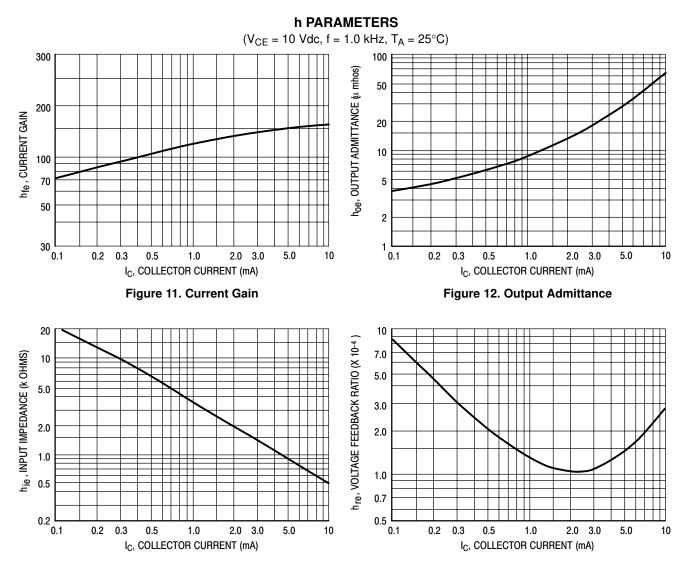
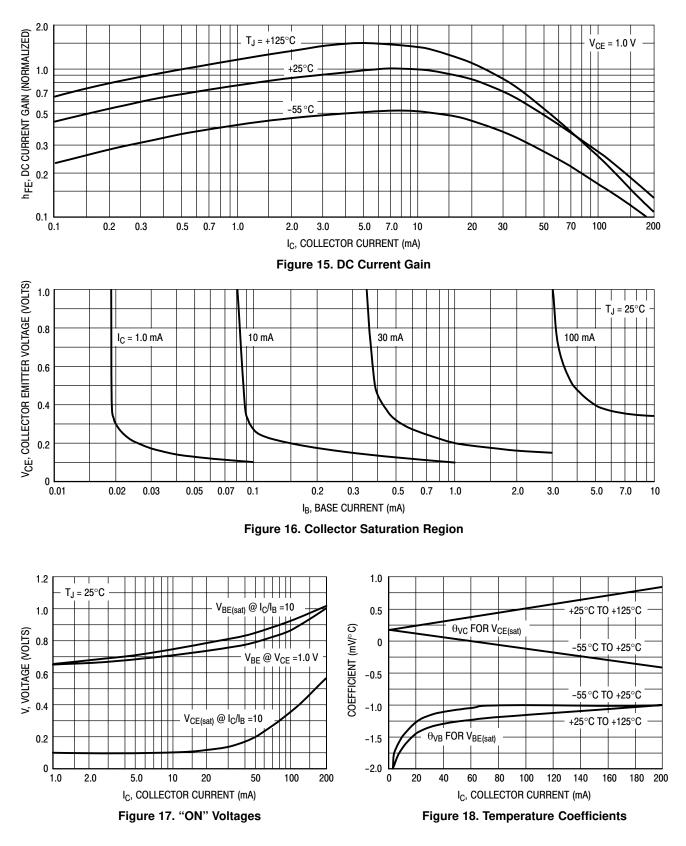


Figure 13. Input Impedance

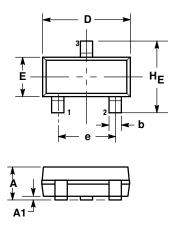
Figure 14. Voltage Feedback Ratio

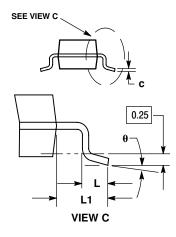
TYPICAL STATIC CHARACTERISTICS



PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
- CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
- BASE MATERIAL. 4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 218, 08

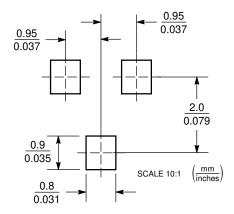
STAI	VDARI	0 310	-00.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

- PIN 1. BASE 2. EMITTER
 - 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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